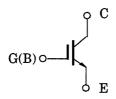
TOSHIBA IGBT Module Silicon N Channel IGBT

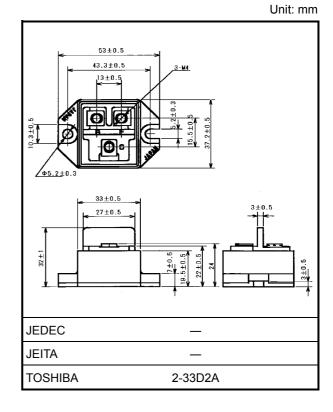
MG75Q1BS11

High Power Switching Applications Motor Control Applications

- Enhancement-mode
- The electrodes are isolated from case.

Equivalent Circuit





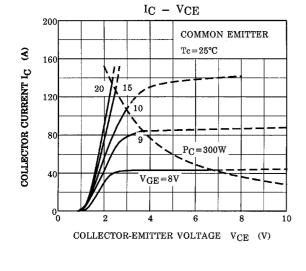
Maximum Ratings (Ta = 25°C)

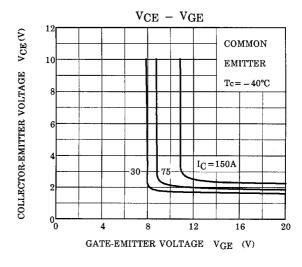
Characteristic		Symbol	Rating	Unit	
Collector-emitter voltage		V _{CES}	1200	V	
Gate-emitter voltage		V _{GES}	±20	V	
Collector current	DC	I _C	75	Α	
	1ms	I _{CP}	150		
Collector power dissipation (Tc = 25°C)		PC	600	W	
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	-40 to 125	°C	
Isolation voltage		V _{Isol}	2500 (AC 1 minute)	٧	
Screw torque (Termina / mounting)		_	2/3	N·m	

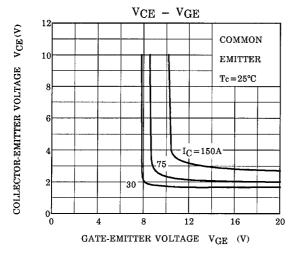
Electrical Characteristics (Ta = 25°C)

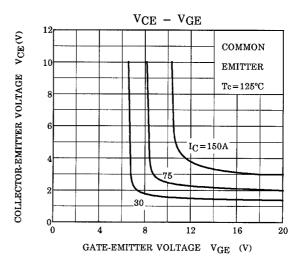
Characteristic		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I _{GES}	V _{GE} =±20V, V _{CE} = 0	_	_	±500	nA
Collector cut-off current		I _{CES}	V _{CE} = 1200V, V _{GE} = 0	_	_	1.0	mA
Gate-emitter cut-off voltage		V _{GE} (OFF)	I _C = 75mA, V _{CE} = 5V	3.0	_	6.0	V
Collector-emitter saturation voltage		V _{CE} (sat)	I _C = 75A, V _{GE} = 15V	_	2.2	2.7	V
Input capacitance		C _{ies}	V _{CE} = 10V, V _{GE} = 0, f = 1MHz	_	10500	_	pF
Switching time	Rise time	t _r	15V 0 16Ω 15V 600V	_	0.3	0.6	- µs
	Turn-on time	t _{on}		_	0.4	0.8	
	Fall time	t _f		_	0.6	1.0	
	Turn-off time	t _{off}		_	1.2	1.8	
Thermal resistance		R _{th (j-c)}	_	_	_	0.208	°C/W

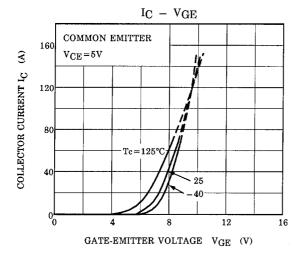
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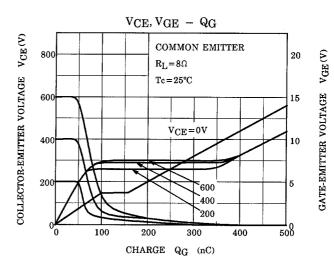






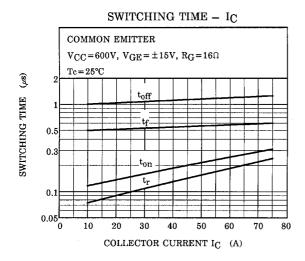


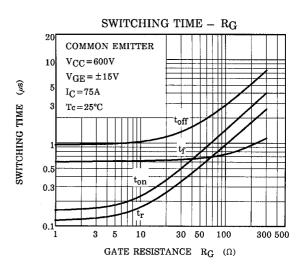


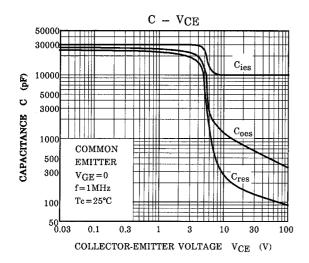


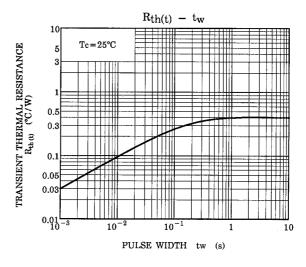
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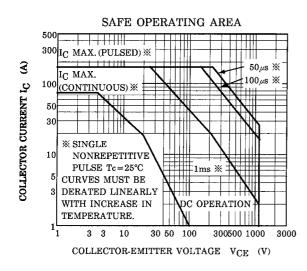
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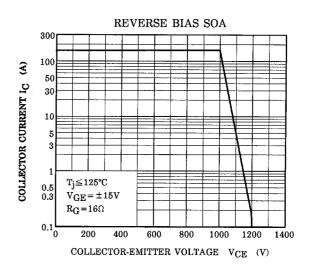












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